PNP/NPN Epitaxial Planar Silicon Transistor

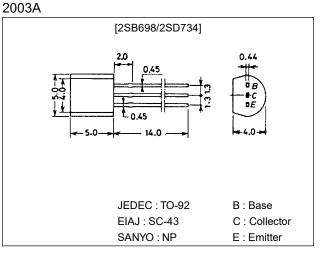


# 2SB698/2SD734

## 1W AF Output, Electronic Governor, DC-DC Converter Applications

### **Package Dimensions**

unit:mm



(): 2SB698 for audio 1W output.

## **Specifications**

#### Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V <sub>CBO</sub>		(–)25	V
Collector-to-Emitter Voltage	V <sub>CEO</sub>		(–)20	V
Emitter-to-Base Voltage	VEBO		(–)5	V
Collector Current	ι <sub>C</sub>		(-)0.7	А
Collector Current (Pulse)	ICP		(–)1.5	А
Collector Dissipation	PC		0.6	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		–55 to +150	°C

#### Electrical Characteristics at Ta = $25^{\circ}C$

Parameter	Symbol	Conditions	Ratings			Unit
Falameter			min	typ	max	Unit
Collector Cutoff Current	I <sub>CBO</sub>	V <sub>CB</sub> =(-)20V, I <sub>E</sub> =0			(–)1.0	μA
Emitter Cutoff Current	IEBO	V <sub>EB</sub> =(-)4V, I <sub>C</sub> =0			(–)1.0	μA
DC Current Gain	h <sub>FE</sub> 1	V <sub>CE</sub> =(-)2V, I <sub>C</sub> =(-)50mA	60*		560*	
	h <sub>FE</sub> 2	V <sub>CE</sub> =(-)2V, I <sub>C</sub> =(-)500mA	50			
Gain-Bandwidth Product	fT	V <sub>CE</sub> =(-)10V, I <sub>C</sub> =(-)50mA		250		MHz
Output Capacitance	Cob	V <sub>CB</sub> =(-)10V, f=1MHz		(13)		pF
				8		pF

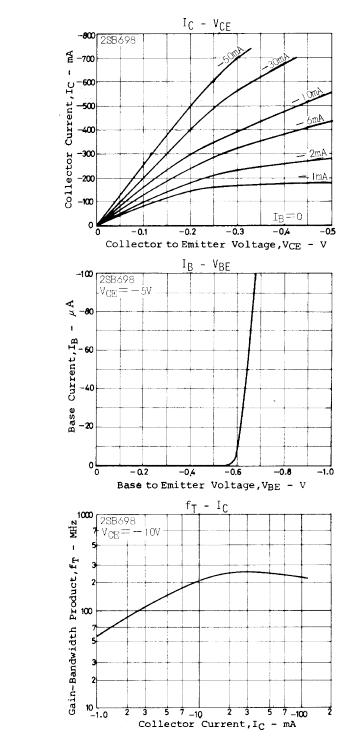
#### $\ast$ : The 2SB698/2SD734 are classified by 50mA $h_{FE}$ as follows :

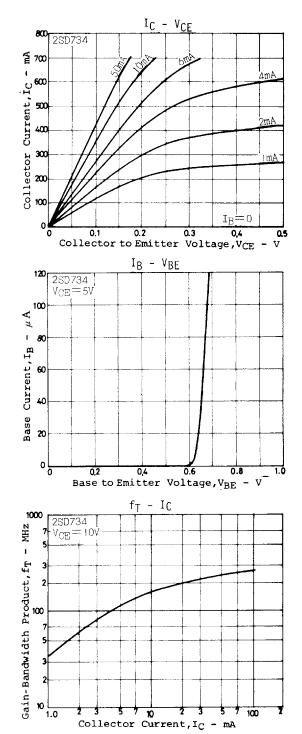
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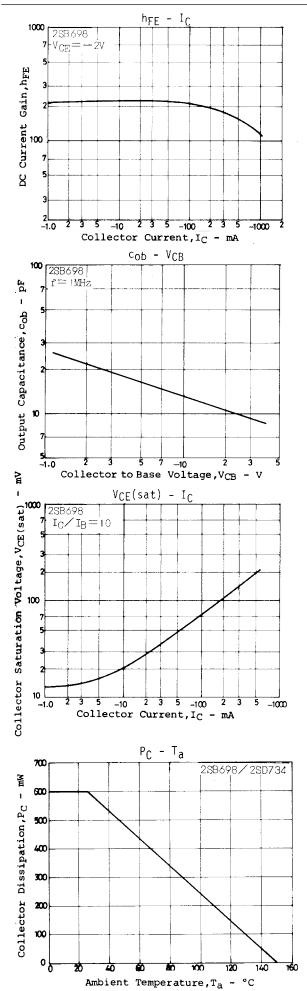
SANYO Electric Co., Ltd. Semiconductor Bussiness Headquaters TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

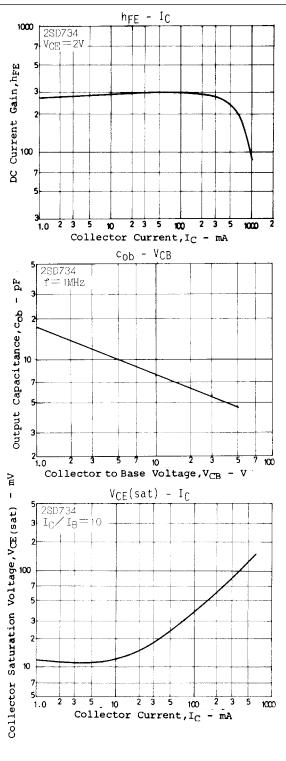
### 2SB698/2SD734

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Collector-to-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =(–)500mA, I <sub>B</sub> =(–)50mA		(-0.2)	(-0.45)	V
				0.13	0.3	V
Base-to-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	I <sub>C</sub> =(-)500mA, I <sub>B</sub> =(-)50mA		(–)0.9		V
Collector-to-Base Breakdown Voltage	V <sub>(BR)</sub> CBO	I <sub>C</sub> =(-)10µA, I <sub>E</sub> =0	(–)25			V
Collector-to-Emitter Brakdown Voltage	V <sub>(BR)</sub> CEO	I <sub>C</sub> =(−)1mA, R <sub>BE</sub> =∞	(–)20			V
Emitter-to-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	I <sub>E</sub> =(-)10μA, I <sub>C</sub> =0	(–)5			V









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